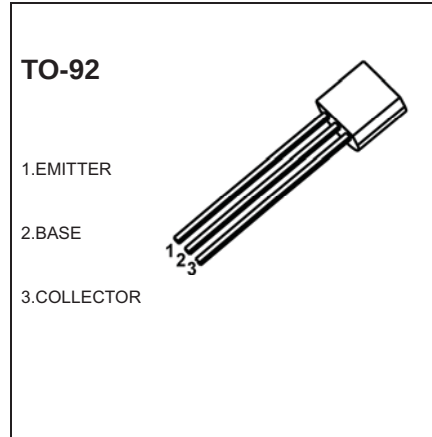


TO-92 Plastic-Encapsulate Transistors

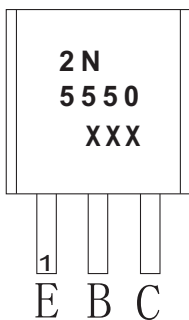
2N5550 TRANSISTOR (NPN)

FEATURES

- Switching and Amplification in High Voltage
- Applications such as Telephony
- Low Current(Max. 600mA)
- High Voltage(Max.160V)

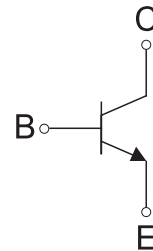


MARKING



2N5550=Device code
 XXX=Code
 GXX=Green molding compound device
 CXX=Normal molding compound device

Equivalent Circuit



ORDERING INFORMATION

Part Number	Package	Packing Method	Pack Quantity
2N5550	TO-92	Bulk	1000pcs/Bag
2N5550-TA	TO-92	Tape	2000pcs/Box

MAXIMUM RATINGS (T_a =25 °C unless otherwise noted)

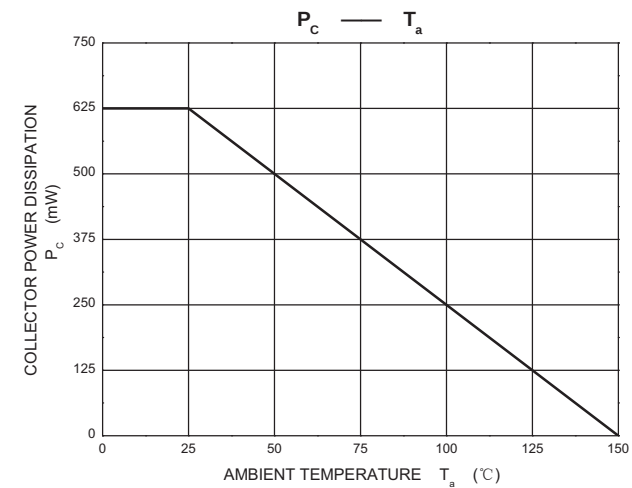
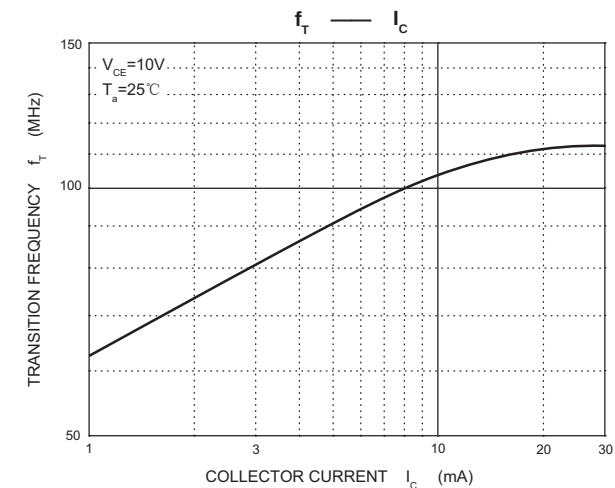
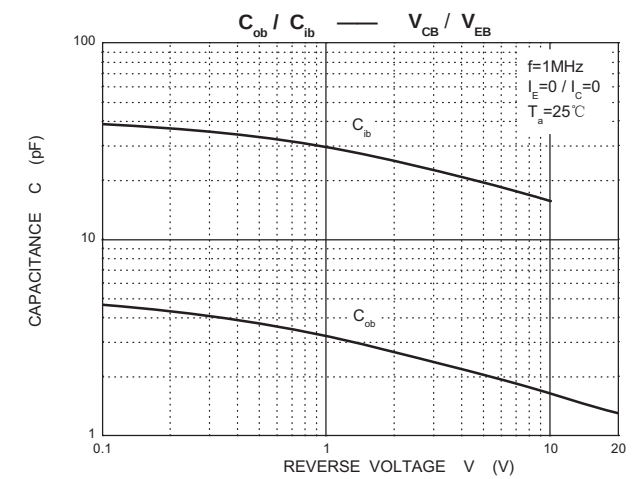
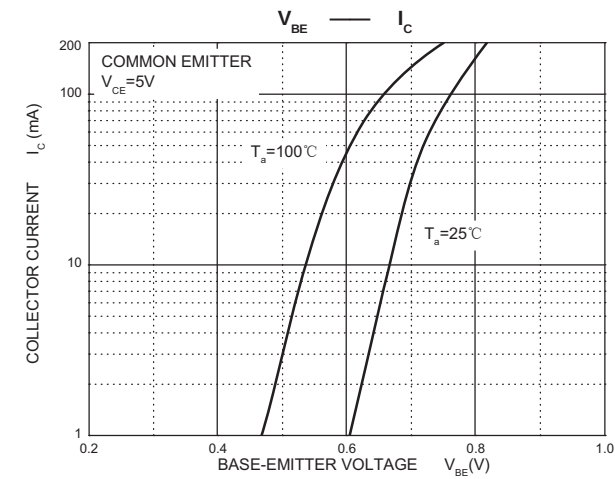
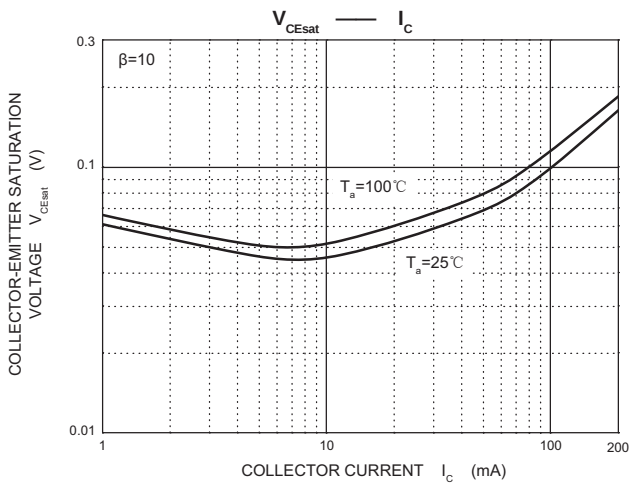
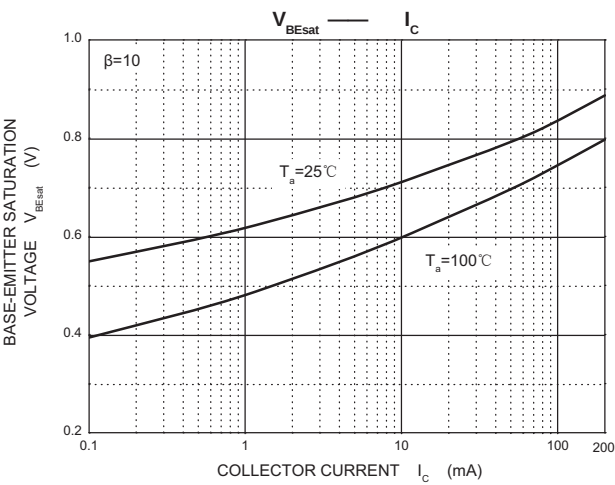
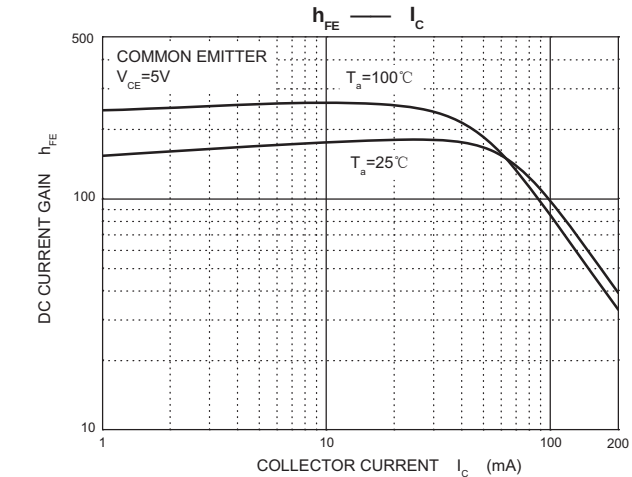
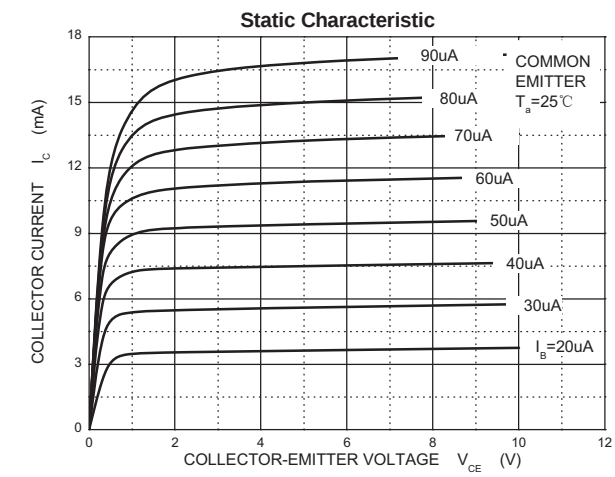
Symbol	Parameter	Value	Unit
V _{CB0}	Collector-Base Voltage	160	V
V _{CE0}	Collector-Emitter Voltage	140	V
V _{EB0}	Emitter-Base Voltage	6	V
I _C	Collector Current -Continuous	0.6	A
P _C	Collector Power Dissipation	0.625	W
T _J ,T _{stg}	Operation Junction and Storage Temperature Range	-55-150	°C

ELECTRICAL CHARACTERISTICS

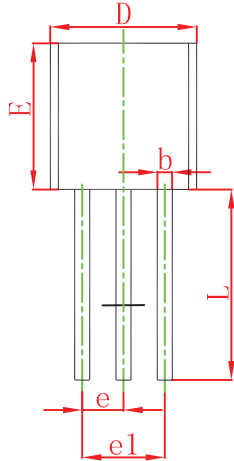
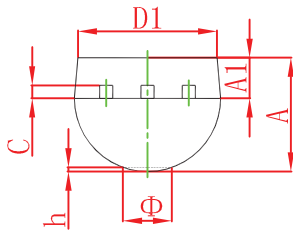
$T_a=25^\circ\text{C}$ unless otherwise specified

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C=100\ \mu\text{A}, I_E=0$	160			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C=1\text{mA}, I_B=0$	140			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E=10\ \mu\text{A}, I_C=0$	6			V
Collector cut-off current	I_{CBO}	$V_{CB}=100\text{V}, I_E=0$			0.1	μA
Emitter cut-off current	I_{EBO}	$V_{EB}=4\text{V}, I_C=0$			0.05	μA
DC current gain	$h_{FE(1)}$	$V_{CE}=5\text{V}, I_C=1\text{mA}$	60			
	$h_{FE(2)}$	$V_{CE}=5\text{V}, I_C=10\text{mA}$	60		250	
	$h_{FE(3)}$	$V_{CE}=5\text{V}, I_C=50\text{mA}$	20			
Collector-emitter saturation voltage	V_{CEsat}	$I_C=10\text{mA}, I_B=1\text{mA}$ $I_C=50\text{mA}, I_B=5\text{mA}$			0.15 0.25	V
Base-emitter saturation voltage	V_{BEsat}	$I_C=10\text{mA}, I_B=1\text{mA}$ $I_C=50\text{mA}, I_B=5\text{mA}$			1 1.2	V
Transition frequency	f_T	$V_{CE}=10\text{V}, I_C=10\text{mA}, f=100\text{MHz}$	100		300	MHz
Collector output capacitance	C_{ob}	$V_{CB}=10\text{V}, I_E=0, f=1\text{MHz}$			6	pF
Noise figure	NF	$V_{CE}=5\text{V}, I_C=0.25\text{mA}, f=1\text{KHz}, R_s=1\text{k}\Omega$			10	dB

Typical Characteristics

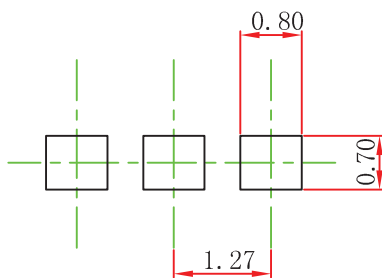


TO-92 Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	3.300	3.700	0.130	0.146
A1	1.100	1.400	0.043	0.055
b	0.380	0.550	0.015	0.022
c	0.360	0.510	0.014	0.020
D	4.300	4.700	0.169	0.185
D1	3.430		0.135	
E	4.300	4.700	0.169	0.185
e	1.270 TYP		0.050 TYP	
e1	2.440	2.640	0.096	0.104
L	14.100	14.500	0.555	0.571
Φ		1.600		0.063
h	0.000	0.380	0.000	0.015

TO-92 Suggested Pad Layout

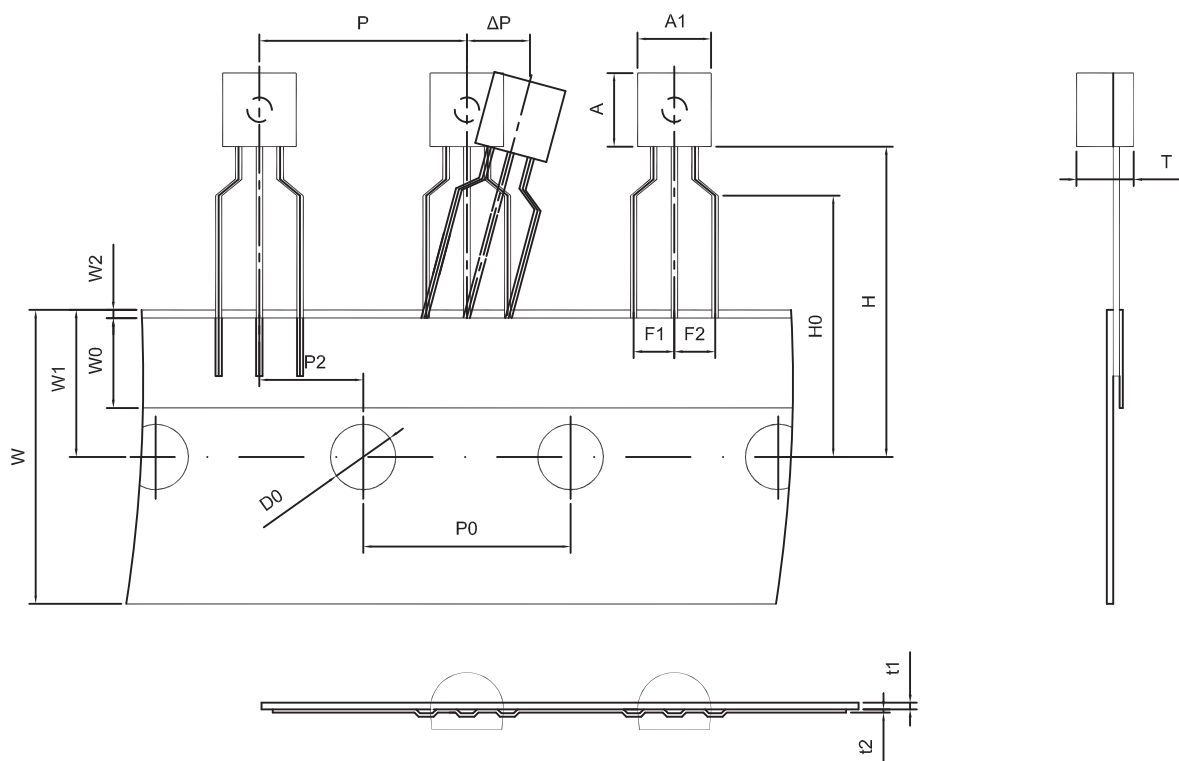


Note:

1. Controlling dimension: in millimeters.
2. General tolerance: $\pm 0.05\text{mm}$.
3. The pad layout is for reference purposes only.

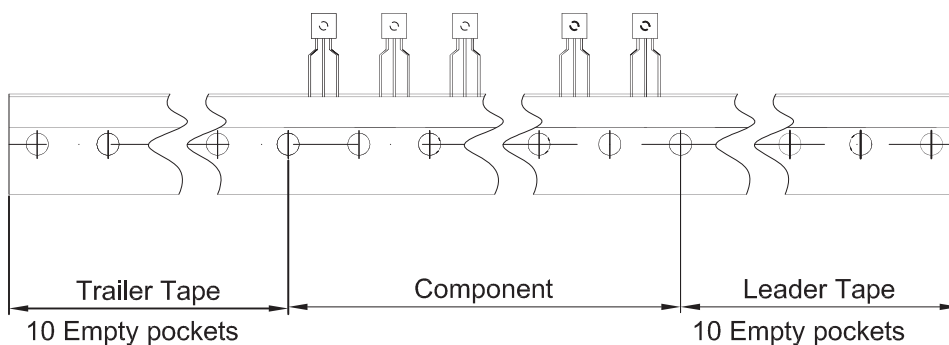
NOTICE

JSCJ reserves the right to make modifications, enhancements, improvements, corrections or other changes without further notice to any product herein. JSCJ does not assume any liability arising out of the application or use of any product described herein.



Dimiensions are in millimeter

A1	A	T	P	P0	P2	F1	F2	W
4.5	4.5	3.5	12.7	12.7	6.35	2.5	2.5	18.0
W0	W1	W2	H	H0	D0	t1	t2	ΔP
6.0	9.0	1.0 MAX.	19.0	16.0	4.0	0.4	0.2	0



Package	Box	Box Size(mm)	Carton	Carton Size(mm)
TO-92	2000 pcs	333×162×43	20,000 pcs	350×340×250